MAX40203

Ultra-Tiny nanoPower, 1A Ideal Diodes with Ultra-Low-Voltage Drop

General Description

The MAX40203 is an ideal diode current-switch with forward voltage drop that is approximately an order of magnitude smaller than that of Schottky diodes. When forward biased and enabled, the MAX40203 conducts with 90mV of voltage drop while carrying currents as high as 1A. During a short-circuit or a fast power-up, the device limits its output current to 2A. The MAX40203 thermally protects itself and any downstream circuitry from overcurrent conditions.

This ideal diode operates from a supply voltage of 1.2V to 5.5V. The supply current is relatively constant with load current, and is typically 300nA. When disabled (EN = low), the ideal diode blocks voltages up to 6V in either direction, makes it suitable for use in most low-voltage, portable electronic devices.

The MAX40203 is available in a tiny, 0.77mm x 0.77mm, 4-bump WLP, with a 0.35mm bump pitch and a 5-pin SOT-23 package. It is specified over the automotive -40°C to +125°C temperature range.

Applications

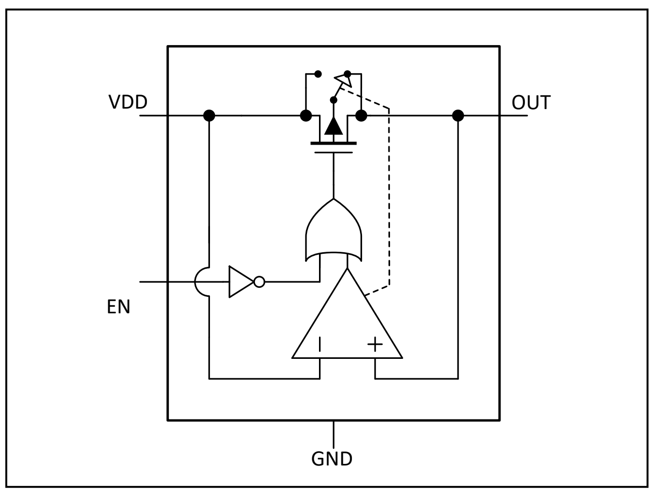
- Notebook and Tablet Computers
- Battery Backup Systems
- Powerline Fault Recorders
- Cellular Phones
- Electronic Toys
- USB-Powered Peripherals
- Portable Medical Devices

Benefits and Features

- Lower Voltage Drop in Portable Applications
  - 14mV Forward Drop at 1mA (WLP)
  - 16mV Forward Drop at 100mA (WLP)
  - 43mV Forward Drop at 500mA (WLP)
  - 90mV Forward Drop at 1A (WLP)
- Longer Battery Life
  - Low Leakage When Reverse-Biased from V_{DD}:
    - 10nA (Typ)
  - Low Supply Quiescent Current
    - 300nA (Typ), 500nA (Max)
- Smaller Footprint Than Larger Schottky Diodes
  - Tiny 0.77mm x 0.77mm 4-Bump WLP
  - SOT23-5 Package
- Wide Supply Voltage Range: 1.2V to 5.5V
- Thermally Self-Protecting
- -40°C to +125°C Operating Temperature Range

Ordering Information appears at end of data sheet.

Simplified Block Diagram



Absolute Maximum Ratings

Any Pin to GND .... -0.3V to +6V
Continuous Current into EN 10mA
Continuous Current Flowing
Between V_{DD} and OUT (WLP).. 1.5A
Continuous Current Flowing
Between V_{DD} and OUT (SOT)... 1A
Continuous Power Dissipation (T_A = +70°C)
(WLP, derate 9.58mW/°C above +70°C).....................766mW
Continuous Power Dissipation (T_A = +70°C)
(SOT, derate 3.90mW/°C above +70°C) 312.60mW
Operating Temperature Range......................... -40°C to +125°C
Junction Temperature .... +150°C
Storage Temperature Range .... -60°C to +165°C
Lead Temperature (soldering, 10s) .... +300°C
Soldering Temperature (reflow) .... +260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Information

4 WLP

Package Code	N40F0+1
Outline Number	21-100273
Land Pattern Number	Refer to Application Note 1891
Thermal Resistance, Four-Layer Board:	
Junction to Ambient (θ_{JA})	104.41°C/W
Junction to Case (θ_{JC})	N/A

5 SOT23

Package Code	U5+2
Outline Number	21-0057
Land Pattern Number	90-0174
Thermal Resistance, Four-Layer Board:	
Junction to Ambient (θ_{JA})	255.90°C/W
Junction to Case (θ_{JC})	81°C/W

For the latest package outline information and land patterns (footprints), go to www.maximintegrated.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

Electrical Characteristics

(V_{DD} = +3.6V, V_{EN} = V_{DD} , C_{IN} = 0.1µF in parallel with 10µF, C_L = 10µF, T_A = -40°C to +125°C. Typical values are at T_A = +25°C, unless otherwise noted (Notes 1, 2).)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
FORWARD BIASED CHARACTERISTICS						
Supply Voltage		Guaranteed by V_{FWD} at 100mA	1.2		5.5	V
Supply Current (Forward Biased, Enabled)	I_{AG}	No load current (I_C = 0), T_A = +25°C		300	500	nA
		No load current (I_C = 0) -40°C < T_A < +85°C			650	nA
		No load current (I_C = 0), -40°C < T_A < +125°C			1.2	µA
Supply Current (Forward Biased, Disabled)		-40°C < T_A < +85°C, V_{EN} = 0V, V_{OUT} = 0V		130	600	nA
		-40°C < T_A < +125°C, V_{EN} =0V, V_{OUT} = 0V		130	2000	
Forward Voltage (V_{DD} – V_{OUT}) (WLP Only)	V_{FWD}	I_{FWD} = 1mA		14	35	mV
		I_{FWD} = 100mA		16	35	
		I_{FWD} = 200mA, V_{DD} = 1.5V		52	75	
		I_{FWD} = 200mA, V_{DD} = 3.6V		21	40	
		I_{FWD} = 500mA		43	90	
		I_{FWD} = 1A (Note 3)		90	200	
Forward Voltage (V_{DD} – V_{OUT}) (SOT23 Only)	V_{FWD}	I_{FWD} = 1mA		14	35	mV
		I_{FWD} = 100mA		28	70	
		I_{FWD} = 200mA, V_{DD} = 1.5V		69	120	
		I_{FWD} = 200mA, V_{DD} = 3.6V		41	90	
		I_{FWD} = 500mA		100	200	
		I_{FWD} = 1A (Note 3)		230	500	
Capacitive Loading		Stable for all load currents (see *Applications* section for further details)		0.3–100		µF
Thermal Protection Threshold		Device temperature at which the MOSFET switch turns off, overriding the Enable pin and the applied voltage polarity		163		°C
Thermal Protection Hysteresis				14		°C
REVERSE-BIASED CHARACTERISTICS						
Turn-Off Reverse Threshold		(V_{OUT} - V_{DD})		26		mV
Leakage Current from V_{DD} (Reverse Biased)	I_{CA}	V_{OUT} = 4V, T_A = +25°C	-50	+10	+50	nA
		V_{OUT} = 4V, -40°C < T_A < +85°C	-150		+150	nA
		V_{OUT} = 5V, T_A = +25°C		15	100	nA
		V_{OUT} = 5V, -40°C < T_A < +125°C	-0.5		+0.5	µA
		V_{DD} = 2.0V, V_{OUT} = 5.5V, -40°C < T_A < +85°C		15	200	nA
Current Into OUT (Reverse Biased)	I_C	V_{OUT} = 4V, T_A = +25°C		350	900	nA
		V_{OUT} = 4V, -40°C < T_A < +85°C			1400	
		V_{OUT} = 5V, T_A = +25°C		360	900	
		V_{OUT} = 5V, -40°C < T_A < +85°C		700	1400	
		V_{OUT} = 5V, -40°C < T_A < +125°C		700	2200	

Electrical Characteristics (continued)

(V_{DD} = +3.6V, V_{EN} = V_{DD} , C_{IN} = 0.1µF in parallel with 10µF, C_L = 10µF, T_A = -40°C to +125°C. Typical values are at T_A = +25°C, unless otherwise noted (Notes 1, 2).)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Leakage Current Into VDD (Reverse Biased, Disabled)	I_{AG}	V_{EN} = 0V, V_{OUT} = 4V	T_A = +25°C	-100	+10	+100	nA
			-40°C < T_A < +85°C	-150		+150	
		V_{EN} = 0V, V_{OUT} = 5V	T_A = +25°C	-100	10	+100	
			-40°C < T_A < +125°C	-500		+500	
ENABLE (EN)							
Low Level Input Current	I_{AE}	V_{EN} = 0V (Note 2)	T_A = +25°C		15	50	nA
			-40°C < T_A < 125°C			0.1	µA
Low Input Voltage Level	V_{IL}					0.4	V
High Input Voltage Level	V_{IH}			1.25			V
High Level Input Current	I_{EG}	V_{EN} = 3.6V (Note 2)	T_A = +25°C			80	nA
High Level Input Current (V_{EN} > V_{DD})	I_{EG}	V_{EN} = 5V (Note 2)	T_A = +25°C		750		nA
			-40°C < T_A < +125°C			1300	nA
Enable Input Hysteresis				10		350	mV
TRANSIENTS AND TIMINGS							
Power-Up Delay					450		µs
Enable Time		Measured from V_{EN} = V_{DD} to the forward current reaching 90% of its final value			320		µs
Disable Time		Load current prior to disabling is 100mA, time measured from V_{EN} = 0 until output current < 1mA			80		µs

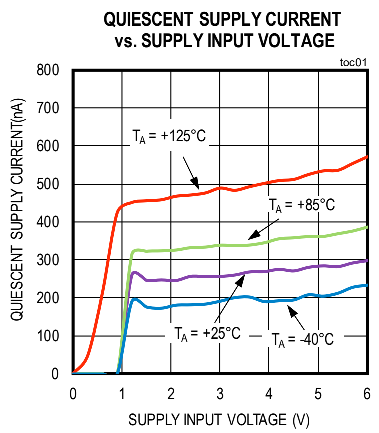
Note 1: Limits are 100% tested at T_A = +25°C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization.

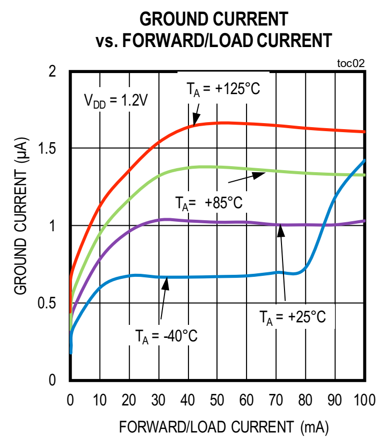
Note 2: Refer to the Supply and Leakage Current Naming Conventions in the *Detailed Description* section for all the different currents that are specified in the *Electrical Characteristics* Table.

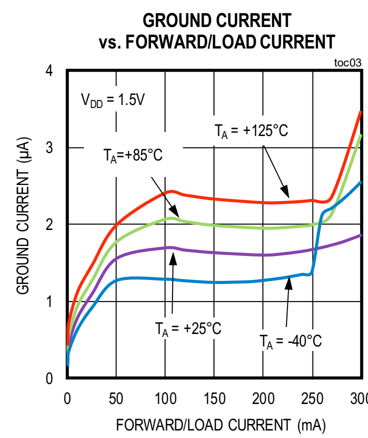
Note 3: 1A pulsed current in duty cycle used for this test to make sure the device's self heating is negligible. For more information, see *Thermal Performance and Power Dissipation* section.

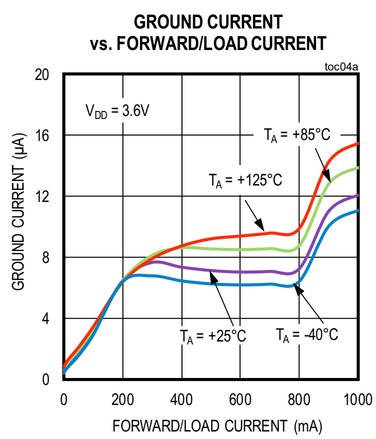
Typical Operating Characteristics

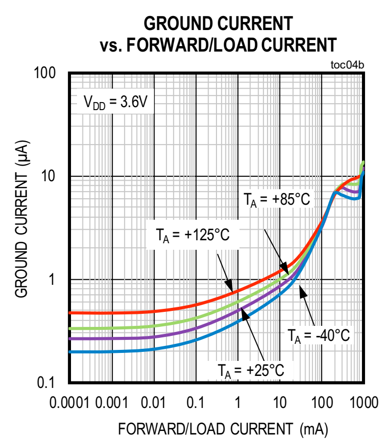
(V_{DD} = 3.6V, GND = 0V, EN = V_{DD}, I_{LOAD} =100mA, C_{OUT} = 10µF to GND. Typical values are at T_A = +25°C, unless otherwise noted.)

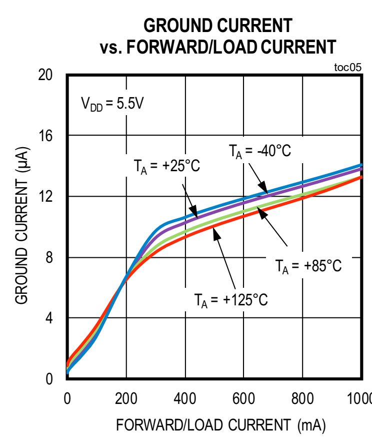


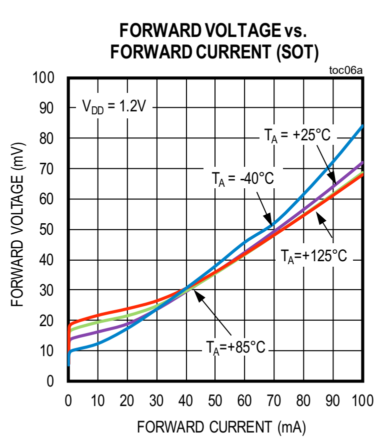


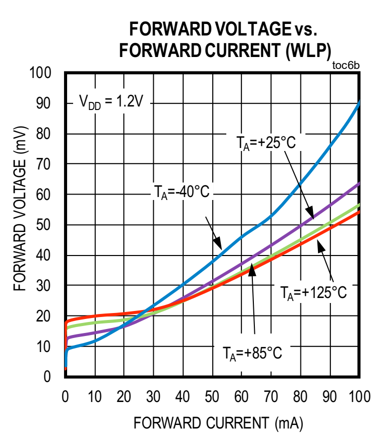


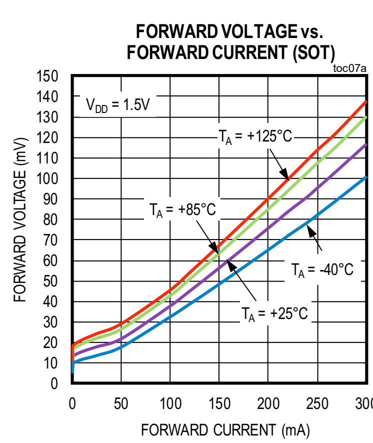








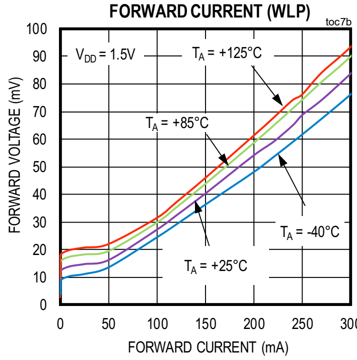




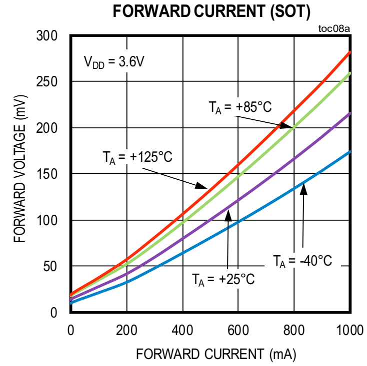
Typical Operating Characteristics (continued)

(V_{DD} = 3.6V, GND = 0V, EN = V_{DD}, I_{LOAD} =100mA, C_{OUT} = 10µF to GND. Typical values are at T_A = +25°C, unless otherwise noted.)

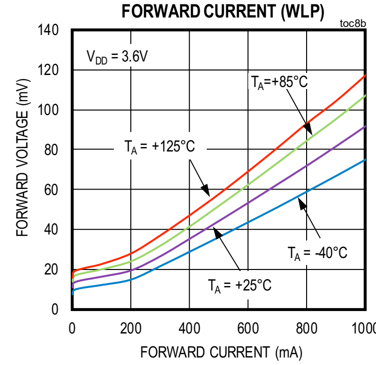
FORWARD VOLTAGE vs. FORWARD CURRENT (WLP)



FORWARD VOLTAGE vs. FORWARD CURRENT (SOT)



FORWARD VOLTAGE vs. FORWARD CURRENT (WLP)



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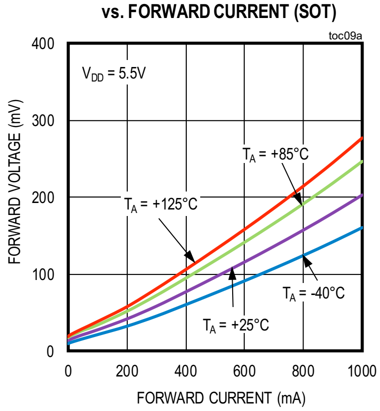
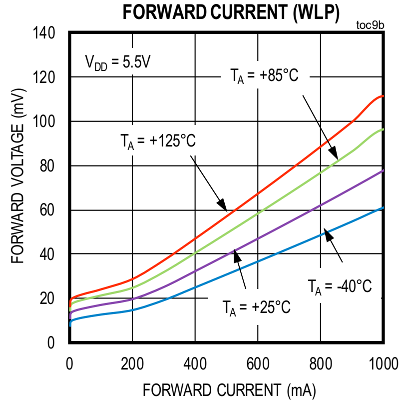
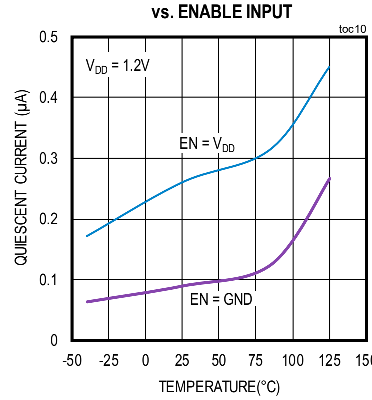


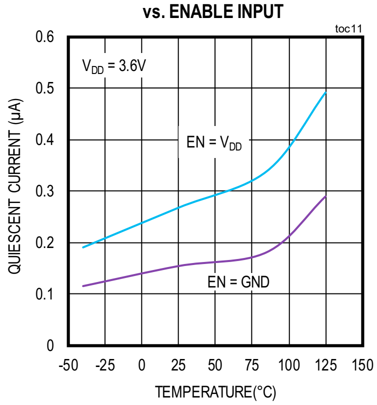
FORWARD VOLTAGE vs. FORWARD CURRENT (WLP)



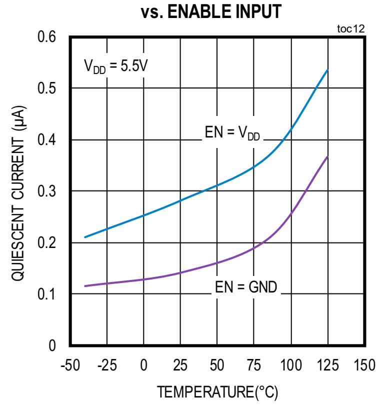
QUIESCENT SUPPLY CURRENT vs. ENABLE INPUT



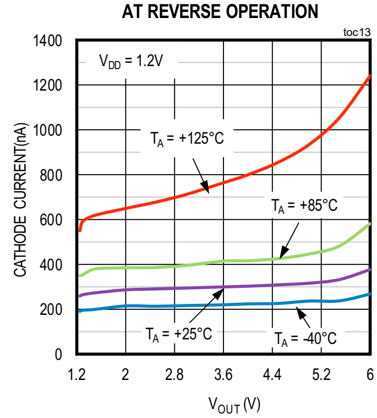
QUIESCENT SUPPLY CURRENT vs. ENABLE INPUT



QUIESCENT SUPPLY CURRENT vs. ENABLE INPUT



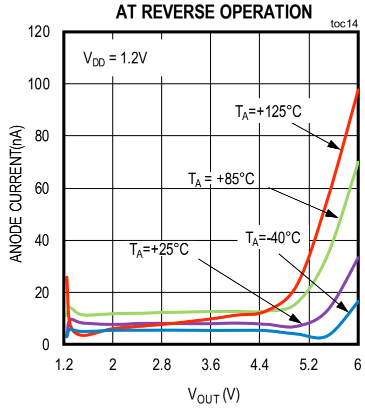
CATHODE CURRENT AT REVERSE OPERATION



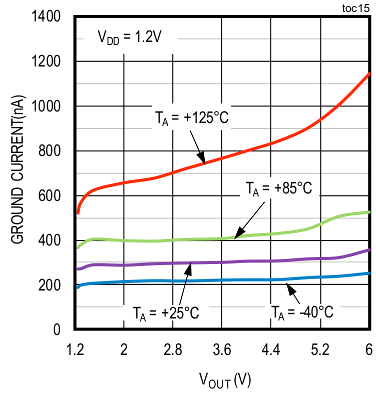
Typical Operating Characteristics (continued)

(V_{DD} = 3.6V, GND = 0V, EN = V_{DD}, I_{LOAD} =100mA, C_{OUT} = 10µF to GND. Typical values are at T_A = +25°C, unless otherwise noted.)

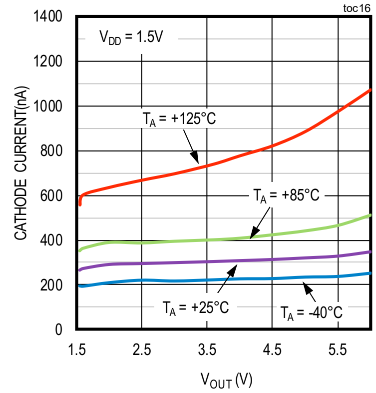
ANODE CURRENT AT REVERSE OPERATION



GROUND CURRENT AT REVERSE OPERATION



CATHODE CURRENT AT REVERSE OPERATION



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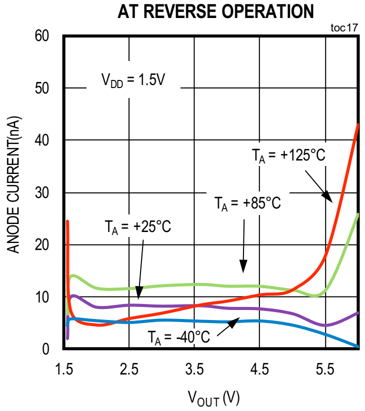
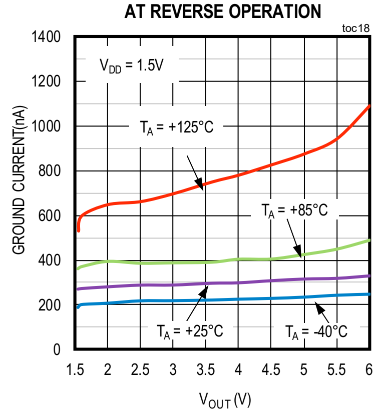


GROUND CURRENT AT REVERSE OPERATION



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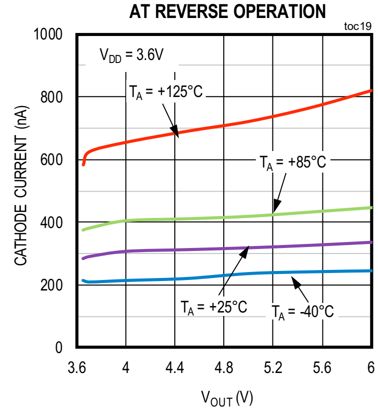
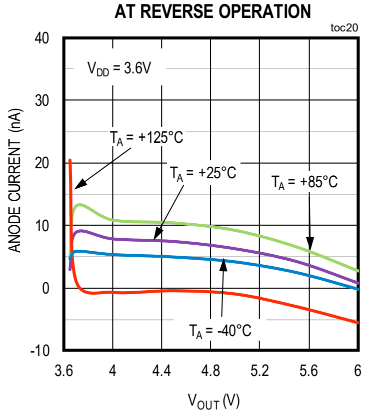
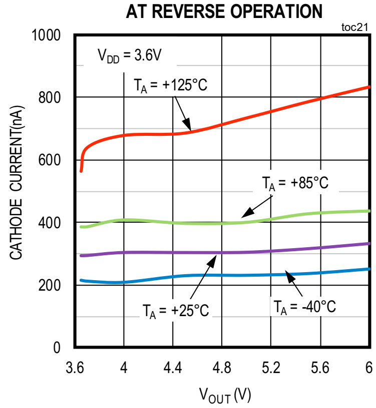


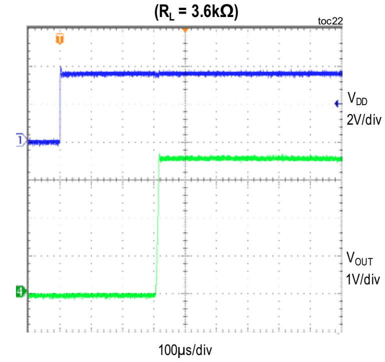
ANODE CURRENT AT REVERSE OPERATION



GROUND CURRENT AT REVERSE OPERATION



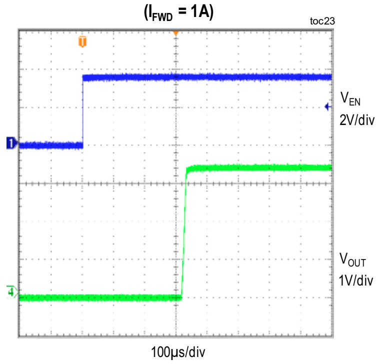
POWER-UP RESPONSE (R_L = 3.6kΩ)



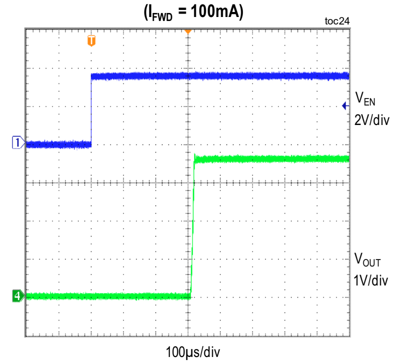
Typical Operating Characteristics (continued)

(V_{DD} = 3.6V, GND = 0V, EN = V_{DD}, I_{LOAD} =100mA, C_{OUT} = 10µF to GND. Typical values are at T_A = +25°C, unless otherwise noted.)

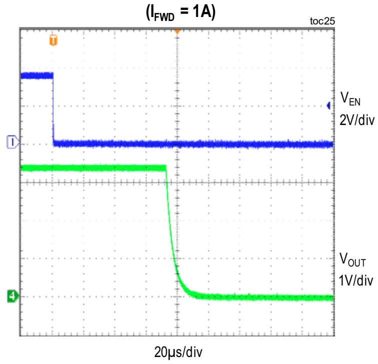
ENABLE TRANSIENT RESPONSE
(I_{FWD} = 1A)
toc23



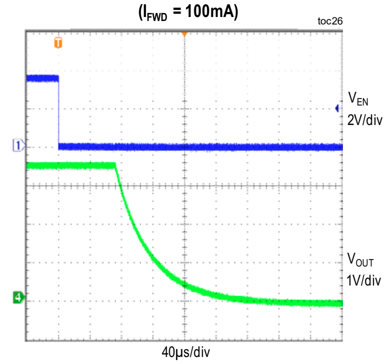
ENABLE TRANSIENT RESPONSE
(I_{FWD} = 100mA)
toc24



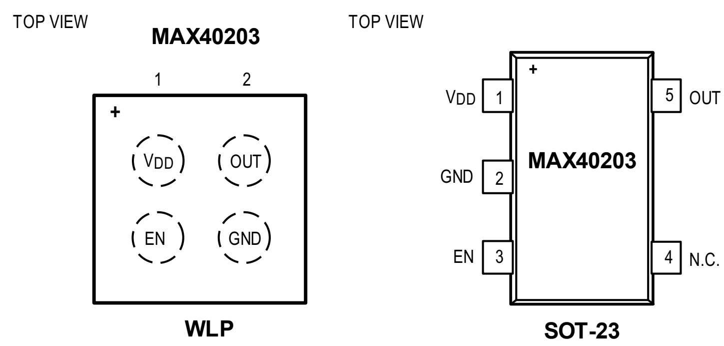
DISABLE TRANSIENT RESPONSE
(I_{FWD} = 1A)
toc25



DISABLE TRANSIENT RESPONSE
(I_{FWD} = 100mA)
toc26



Pin Configuration



Pin Description

PIN		NAME	FUNCTION
WLP	SOT23		
A1	1	V_{DD}	Input Current (Diode Anode) and Supply Voltage when $V_{DD} > V_{OUT}$
A2	5	OUT	Current Output (or Diode Cathode). OUT is also the internal supply when $V_{OUT} > V_{DD}$.
B1	3	EN	Active-High Enable Input with a Weak Internal Pullup. Drive EN high to enable the device, and pull it low to disable the device.
B2	2	GND	Ground. Power supply return.
—	4	N.C.	No Connection. Not internally connected.

Detailed Description

The MAX40203 mimics a near-ideal diode. The device blocks reverse-voltages and passes current when forward biased just as a conventional discrete diode does. However, instead of a cut-in voltage around 500mV and a logarithmic voltage-current transfer curve, these ideal diodes exhibit a near-constant voltage drop independent of the magnitude of the forward current. This voltage drop is around 43mV at 500mA of forward current.

The near-constant forward voltage drop helps with supply regulation; a conventional diode's voltage drop typically increases by 60mV for every decade change in forward current. Similar to normal diodes, these ideal diodes also become resistive as the forward current exceeds the specified limit (see Figure 1). Unlike conventional diodes, ideal diodes include automatic thermal protection; if the die temperature exceeds a safe limit, they turn off in order to protect themselves and the circuitry connected to them. Like a conventional diode, the ideal diode turns off when reverse-biased. The turn-on and turn-off times for enable and disable responses are similar to those of forward and reverse-bias conditions.

The MAX40203 features an active-high enable input (EN) that allows the forward current path to be turned off when not required. The device is disabled when EN is low, and the ideal diode blocks voltages on either side to a maximum of 6V above ground. This feature allows these ideal diodes to be used to switch between power supply sources, or to control which sub-systems are to be powered up. The EN input has an internal weak pullup, it can be left open for normal operation (for -40°C to +85°C), or connect to V_{DD} for full temperature operating range. EN should not be turned on before V_{DD}.

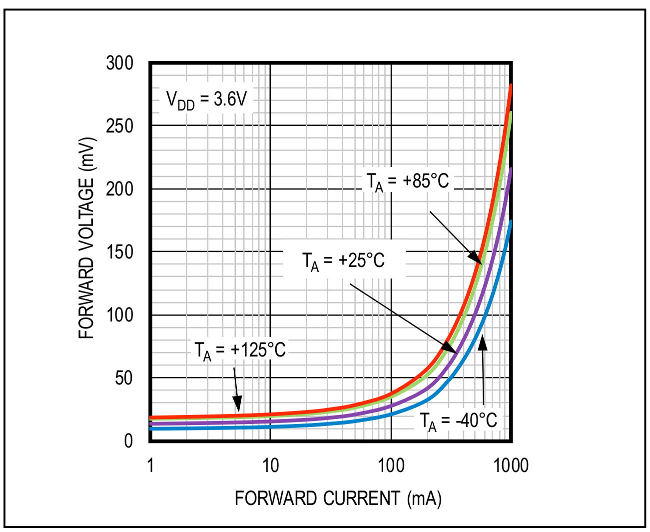


Figure 1. Forward Voltage vs. Forward Current

It should be noted, however, that these ideal diodes are designed to be used to switch between different DC sources, and not for rectifying AC. In applications where an input voltage that is negative with respect to ground may be applied to the diode, conventional diodes should be used.

Principle of Operation

The MAX40203 uses an internal P-channel MOSFET to pass the current from the VDD input to the OUT output. The internal MOSFET is controlled by circuitry that:

1) Switches on the MOSFET (enable input is high), the MAX40203 is forward biased.
2) Turns the MOSFET off when the V_{OUT} is greater than V_{DD}.
3) Turns the MOSFET off if the enable input is pulled low.
4) Turns off the MOSFET when the die temperature exceeds the thermal protection threshold.

Supply and Leakage Current Naming Convention

Figure 2 describes the naming conventions for all the different currents that are specified in the *Electrical Characteristics* table.

In forward biased mode: I_A is the current entering into the V_{DD} pin. I_{AC} is the current entering the V_{DD} pin and exiting from the OUT pin. I_{AG} the current entering the V_{DD} pin and exiting from the GND pin.

$$I_A \text{ (forward biased)} = I_{AG} + I_{AC}$$

Likewise, in reverse biased mode: I_{CA} is the fraction of the current that enters the OUT pin and exits from the V_{DD} pin. There is also an I_{CG}, in reverse bias conditions, enters in the OUT pin and exits from the GND pin.

$$I_C \text{ (reverse biased)} = I_{CA} + I_{CG}$$

The supply current is defined as the current entering the V_{DD} pin (I_{AG}), when $V_A \geq V_C$, no load current, and EN is floating. This current all flows to GND.

The leakage current under reverse biased conditions (I_{CA}) is the current exiting from the V_{DD} pin. This current enters the device from the OUT pin. There is also a current that flows from the OUT pin to the GND pin (I_{CG}). Thus, $I_C = I_{CA} + I_{CG}$. Note that I_{CA} is proportional to the magnitude of the reverse bias. The I_{CG} current is essentially the supply current, it is less sensitive to the magnitude of the reverse bias.

The high input level current, I_{EG}, when $V_{EN} > V_{DD}$ is a current that flows only to GND.

Applications Information

Loading Limitations

Due to the very low quiescent current of these ideal diodes, the internal control circuitry has limited response speed. Therefore, when the load contains significant capacitance and currents are high (> 500mA), both the turn-on time and the turn-off time can be noticeable. In most situations this is unlikely to be an issue, but the source impedance needs to be within certain limits if the source voltage is below 2V. This is because a sufficiently large current surge can drop the input voltage to below the minimum supply, causing the internal circuitry to start to shut down.

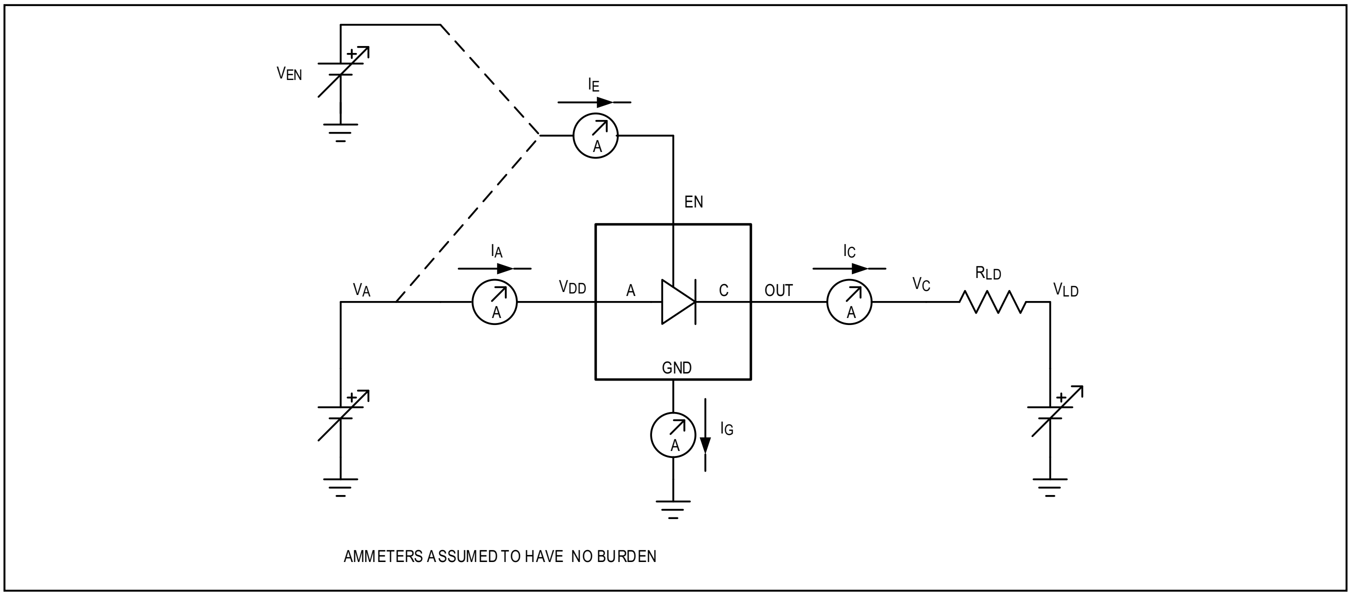


Figure 2. Ideal Diode Test Setup and Naming Convention

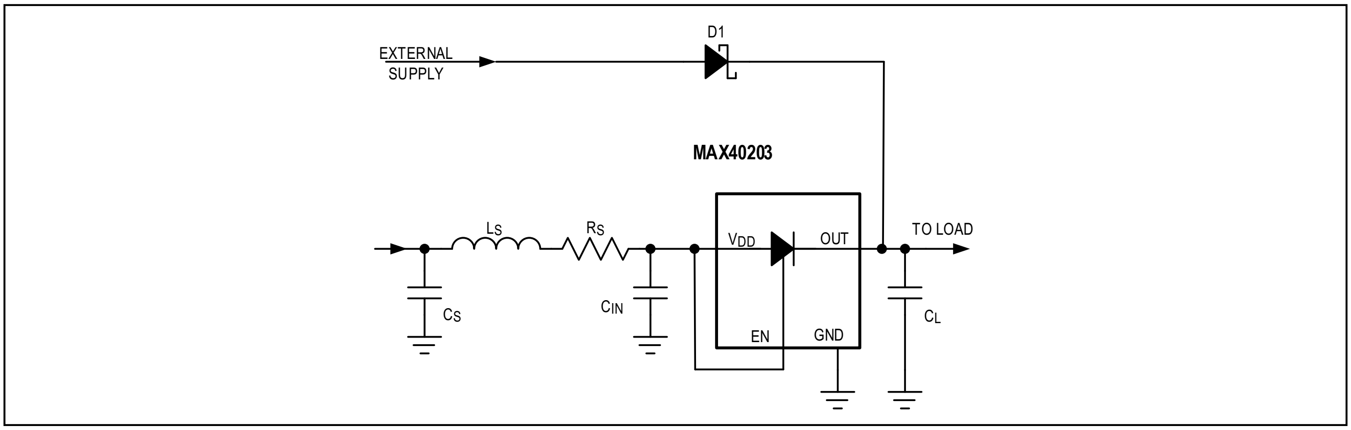


Figure 3. Typical OR Application Showing Source Impedance

In Figure 3, the input source inductance and resistance are shown. When a sudden current step occurs, the ideal diode becomes forward biased and turns on, and the resulting current surge causes a momentary drop across L_S and R_S. Placing C_S very close to the V_{DD} pin reduces both L_S and R_S. Adding larger capacitance load is recommended for better load step response.

Thermal Performance and Power Dissipation

The MAX40203 is not designed to operate in continuous thermal fault conditions greater than 150°C. If the junction temperature rises to well above T_J = +150°C, an internal thermal sensor signals the shutdown logic, which turns off the MOSFET, allowing the IC to cool. The thermal sensor turns the MOSFET on again after the IC's junction temperature cools by roughly 14°C. The shutdown logic is intended to protect against short-term transient thermal faults, not continuous over-temperature conditions. A continuous over-temperature condition can result in a cycled output (Figure 4) with an average temperature greater than 150°C and should be avoided. During continuous operation, do not exceed the absolute maximum junction temperature rating of T_J = +150°C.

Although the MAX40203's operating range is -40°C ≤ T_A ≤ +125°C, care must be taken when using heavy loads (e.g., I_{FWD} above 500mA to 1A). The forward voltage drop across the V_{DD} and OUT pins increases linearly with forward current when the forward current is high. In this resistive region, the dissipation increases with the square of the forward current.

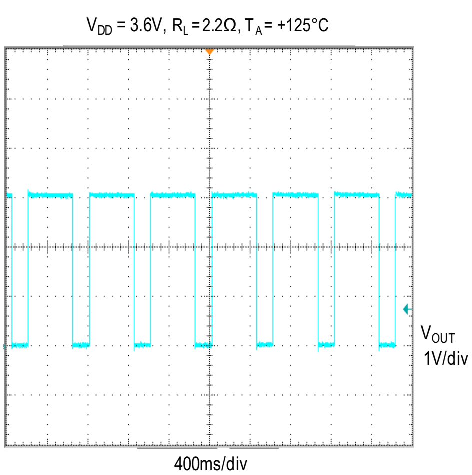


Figure 4. Cycled Output During Continuous Thermal Overload Condition

The power dissipation is the differential voltage (V_{FWD}) multiplied by the current passed by the device (I_{FWD}). The quiescent current has a negligible effect. The ambient temperature is essentially the PCB temperature, since this is where all the heat is sunk to. Therefore, the die temperature rise is [V_{FWD} x I_{FWD} x θ_{JA}] + T_A, where T_A is the temperature of the board or ambient temperature.

Example calculations follow for power dissipation and die temperature for SOT package.

SOT-23:

Because the SOT-23 package has a higher thermal resistance than the WLP, we'll reduce the forward current by 50%, yielding I_{FWD} = 500mA, V_{FWD} = 175mV (maximum value at 500mA), T_A = 85°C.

$$P_{DIS} = 500mA \times 175mV = 87.5mW.$$

Package Derate Calculation:

From the Absolute Maximum Ratings, the Maximum Power Dissipation up to 70°C is 312.6mW. At 85°C ambient temperature, the maximum power dissipation is:

$$312.6mW – [(85°C - 70°C) \times 3.9mW/°C] = 253.5mW.$$

The power dissipation determined above is 87.5mW, so it is well within the limit. Note that, due to the SOT-23's higher thermal resistance, a continuous forward current of 1A would be above the limit.

The junction temperature is

85°C + (87.5mW/3.9mW/°C) = 85°C + 22.4°C = 107.4°C,

which is well below the maximum rating.

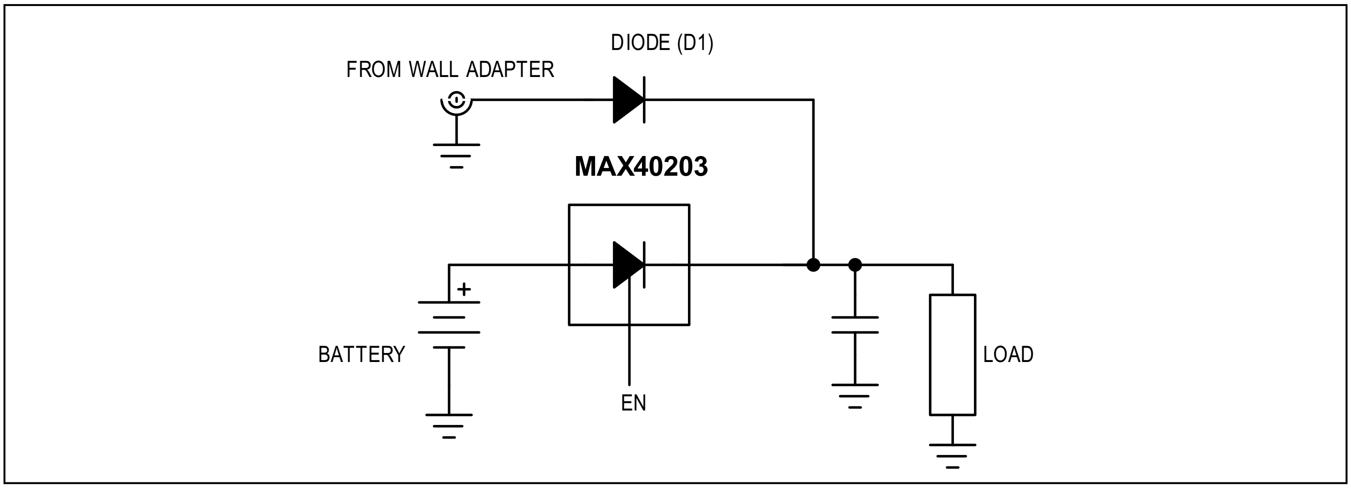
Note that for I_{FWD} =1A, the worst-case forward voltage increases to 500mV, yielding a power dissipation of 500mW, which is greater than the maximum limit, and would be expected to trip the thermal shutdown.

Typical Application Circuits

Typical Application: Battery and Wall-Adapter Power-ORing

A typical use for an ideal diode is to serve as a diode with very low voltage drop in a simple power supply ORing circuit for portable electronics. The low, <50mV, drop is a significant improvement compared to any diode of similar size. In many systems, the wall-adapter has sufficient output capability that it can use a standard, cheap diode while the ideal diode is used for the battery circuit. However, an ideal diode can be used for D1 as well to maximize efficiency even when powered from the wall adapter.

The ideal diode has far lower reverse leakage at higher temperatures than typical large schottky diodes. As a result, the ideal diode can be used with primary cells without danger of damaging them.

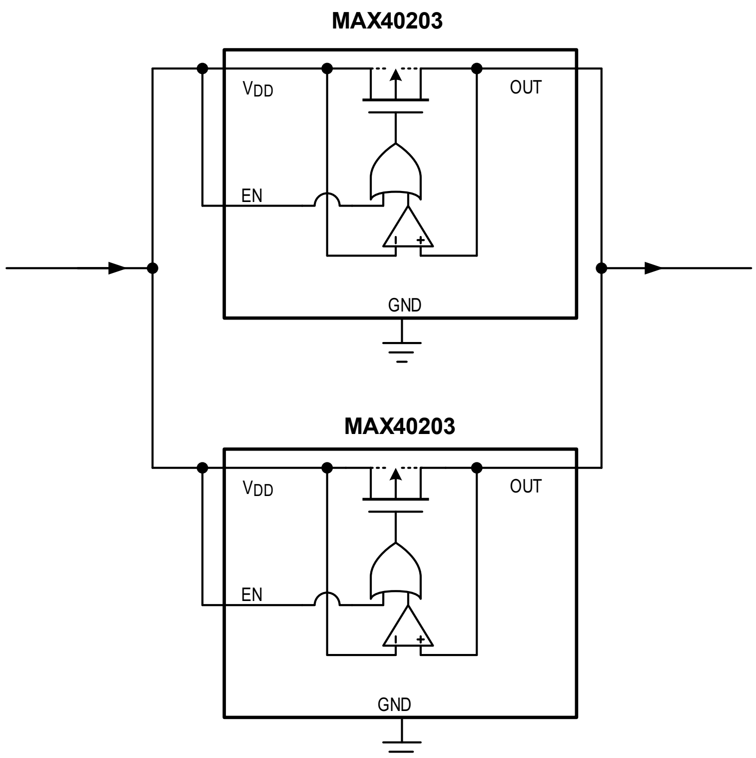


Higher Currents Using Paralleled Ideal Diodes

Since the ideal diode current flows through a mosfet, placing two or more in parallel will safely increase the current handling capability. This relies on the strong positive temperature coefficient of mosfets, so by keeping the paralleled units in close thermal contact, they will inherently share the current.

The figure below shows two units in parallel; this can be extended to multiple units as needed. The upper limit depends on close thermal tracking; up to six units is generally practical when using the WLP versions. If possible, use 2oz copper for the PCB's top metal to help with the thermal connection and keep the units as close together as practical.

Typical Application Circuits (continued)



Ordering Information

PART	TEMP RANGE	PIN-PACKAGE	TOP MARK
MAX40203ANS+T	-40°C to +125°C	4 WLP	+H
MAX40203AUK+T	-40°C to +125°C	5 SOT23	AMJO

+ Denotes a lead(Pb)-free/RoHS-compliant package.
T = Tape-and-reel.

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	6/18	Initial release	—
1	3/19	Updated *General Description*, *Benefits and Features*, *Electrical Characteristics*, *Typical Operating Characteristics*, *Detailed Description*, and *Ordering Information*	1, 3, 5, 6, 9, 13

For pricing, delivery, and ordering information, please visit Maxim Integrated's online storefront at https://www.maximintegrated.com/en/storefront/storefront.html.

